

## Low IR Schottky barrier diode

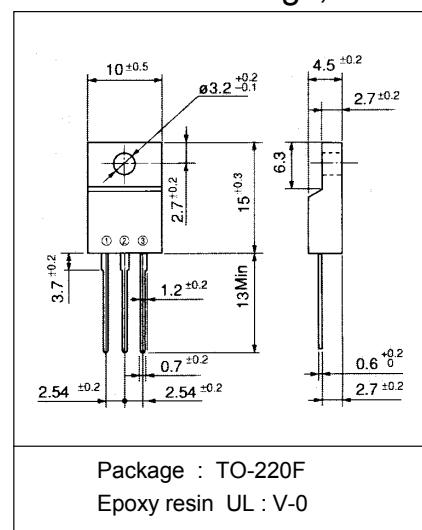
### ■ Features

- Low IR
- Low VF
- Center tap connection

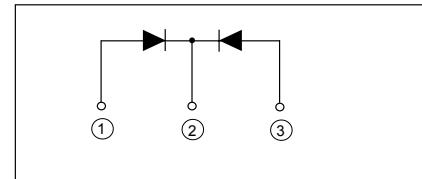
### ■ Applications

- High frequency operation
- DC-DC converters
- AC adapter

### ■ Outline drawings, mm



### ■ Connection diagram



### ■ Maximum ratings and characteristics

#### ● Maximum ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak surge reverse voltage	$V_{RSM}$	$t_w=500\text{ns}$ , duty=1/40	100	V
Repetitive peak reverse voltage	$V_{RRM}$		100	V
Isolating voltage	$V_{iso}$	Terminals-to-Case, AC.1min.	1500	V
Average output current	$I_o$	Square wave, duty=1/2 $T_c=118^\circ\text{C}$	10 *	A
Non-repetitive surge current	$I_{FSM}$	Sine wave 10ms	125	A
non-repetitive reverse surge power dissipation	$PRM$	$t_w=10\mu\text{s}$ , $T_j=25^\circ\text{C}$	330	W
Operating junction temperature	$T_j$		+150	$^\circ\text{C}$
Storage temperature	$T_{stg}$		-40 to +150	$^\circ\text{C}$

\* Out put current of center tap full wave connection

#### ● Electrical characteristics (at $T_a=25^\circ\text{C}$ Unless otherwise specified )

Item	Symbol	Conditions	Max.	Unit
Forward voltage **	$V_F$	$I_F=5\text{A}$	0.86	V
Reverse current **	$I_R$	$V_R=100\text{V}$	150	$\mu\text{A}$
Thermal resistance	$R_{th(j-c)}$	Junction to case	3.5	$^\circ\text{C}/\text{W}$

\*\*Rating per element

#### ● Mechanical characteristics

Mounting torque	Recommended torque	0.3 to 0.5	$\text{N}\cdot\text{m}$
Approximate mass		2	g

## ■ Characteristics

